

Serial No.: 10/535,366  
Docket No.: 09792909-6253  
Amendment dated July 7, 2008  
Reply to the Office Action of March 6, 2008

## IN THE ABSTRACT OF THE DISCLOSURE

Please amend the abstract as follows:

A solid-state imaging device is capable of simplifying the a pixel structure to reduce the a pixel size and capable of suppressing the a variation in the characteristics between the pixels when a plurality of output systems is are provided. A unit cell (30) includes two pixels (31) and (32), Upper having upper and lower photoelectric converters (33) and (34), transfer transistors (35) and (36) connected to the upper and lower photoelectric converters, respectively, a reset transistor (37), and an amplifying transistor (38) form the two pixels (31) and (32). A full-face signal line 39 is connected to the respective drains of the reset transistor (37) and the amplifying transistor (38). Controlling the full-face signal line (39), along with transfer signal lines (42) and (43) and a reset signal line (41), to read out signals realizes the simplification of the simplifies wiring in the pixel, the and permits reduction of the pixel size, and so on.